HMC263LP4E

GaAs MMIC LOW NOISE AMPLIFIER, 24 - 36 GHz

Typical Applications

The HMC263LP4E is ideal for:

- Millimeterwave Point-to-Point Radios
- LMDS
- VSAT
- SATCOM

Features

Low Noise Figure: 2.2 dB

High Gain: 20 dB

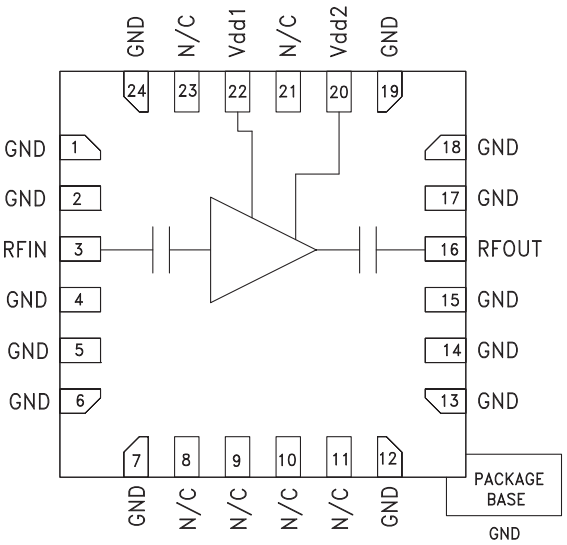
Single Positive Supply: +3V or +5V

DC Blocked RF I/Os

No External Matching

24 Lead 4x4mm QFN Package: 16mm²

Functional Diagram



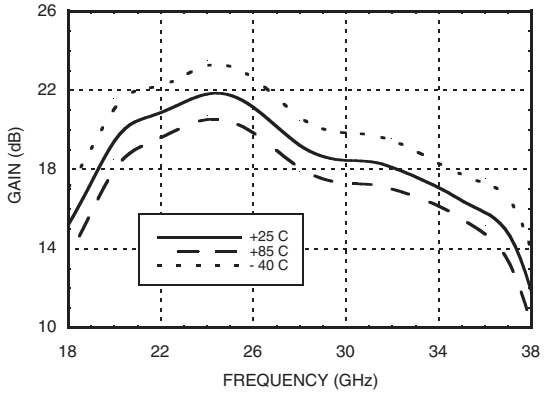
General Description

The HMC263LP4E is a GaAs MMIC Low Noise Amplifier (LNA) which covers the frequency range of 24 to 36 GHz and is housed in a leadless plastic SMT package. The HMC263LP4E utilizes a GaAs PHEMT process offering 20 dB gain from a single bias supply of + 3V @ 58 mA with a noise figure of 2.2 dB. The HMC263LP4E may be used in conjunction with HMC264LC3B or HMC265LM3 mixers to realize a millimeterwave system receiver. The RF I/Os are DC blocked and matched to 50 Ohms requiring no external components.

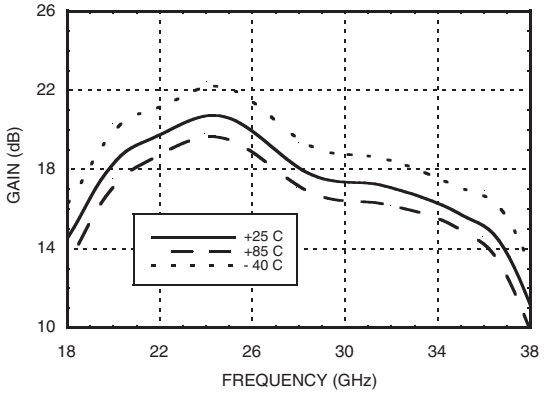
Electrical Specifications, T_A = +25° C, Vdd = +3V

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range		24 - 27			27 - 32			32 - 36		GHz
Gain	19	21	27	17	19	23	15	17	20	dB
Gain Variation Over Temperature		0.03			0.03			0.03		dB/°C
Noise Figure		2.0	3.0		2.2	3.0		2.5	4.0	dB
Input Return Loss		12			9			11		dB
Output Return Loss		10			9			9		dB
Output Power for 1 dB Compression (P1dB)		6			8			9		dBm
Saturated Output Power (Psat)		9			11			12		dBm
Output Third Order Intercept (IP3)		16			18			20		dBm
Supply Current (Idd) (@ Vdd = +3.0V)		58	77		58	77		58	77	mA

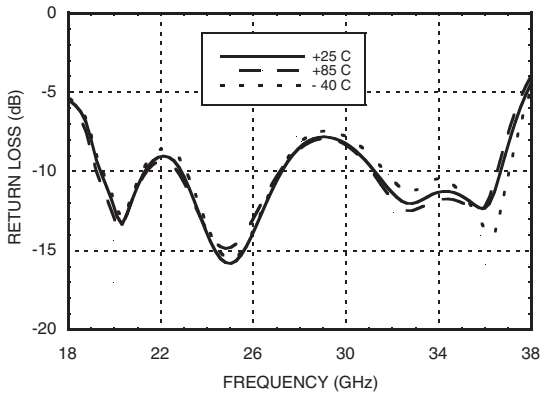
Gain vs. Temperature @ Vdd = +3V



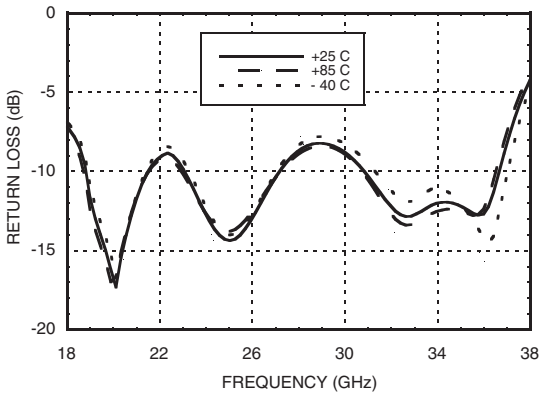
Gain vs. Temperature @ Vdd = +5V



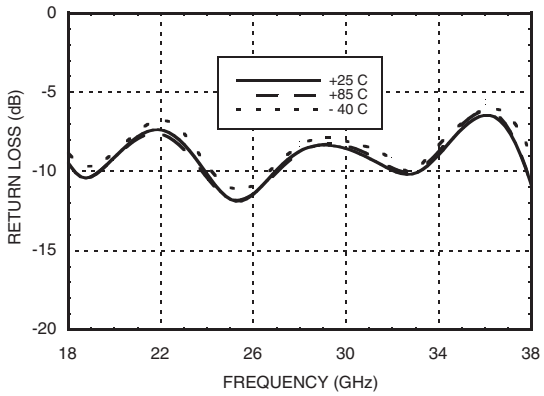
Input Return Loss @ Vdd = +3V



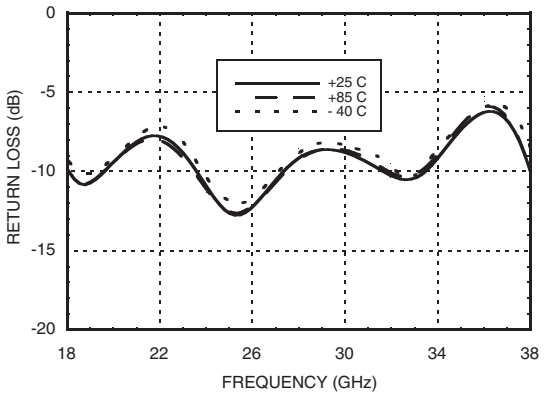
Input Return Loss @ Vdd = +5V



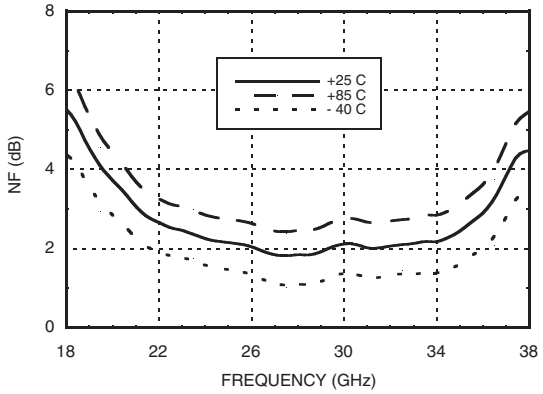
Output Return Loss @ Vdd = +3V



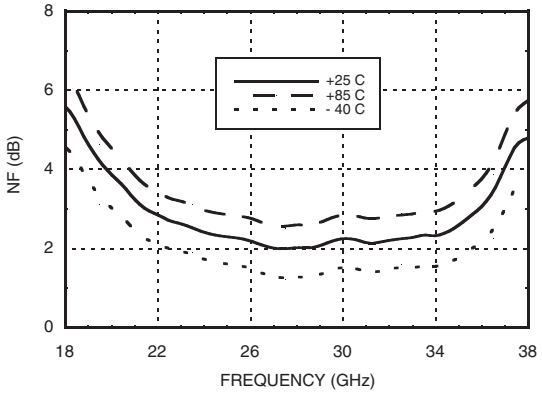
Output Return Loss @ Vdd = +5V



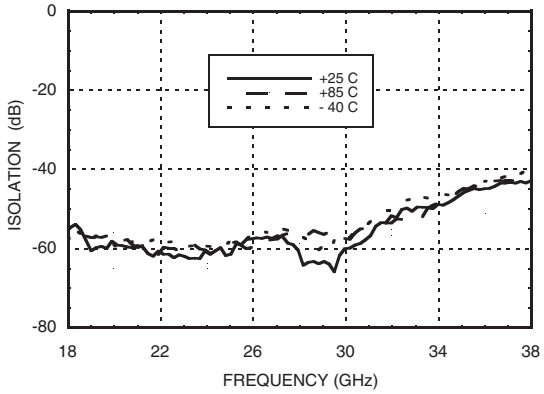
Noise Figure vs. Temperature @ Vdd = +3V



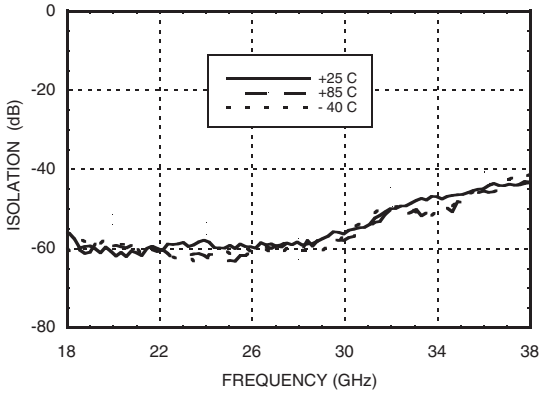
Noise Figure vs. Temperature @ Vdd = +5V



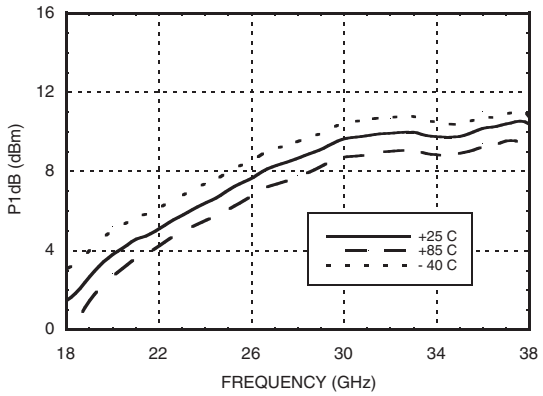
Isolation @ Vdd = +3V



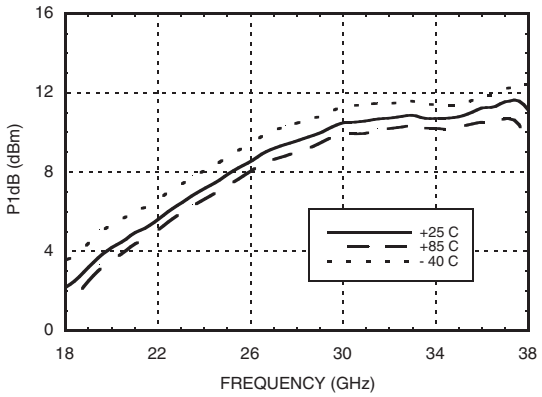
Isolation @ Vdd = +5V



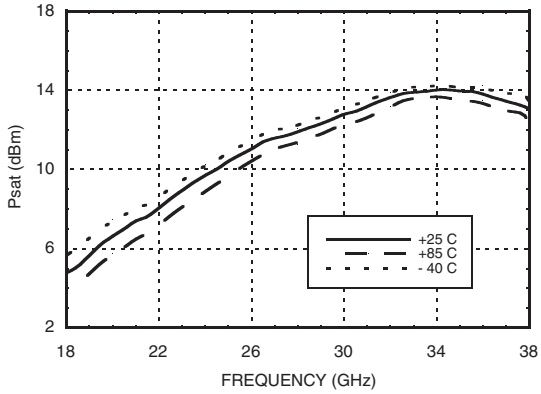
Output P1dB @ Vdd = +3V



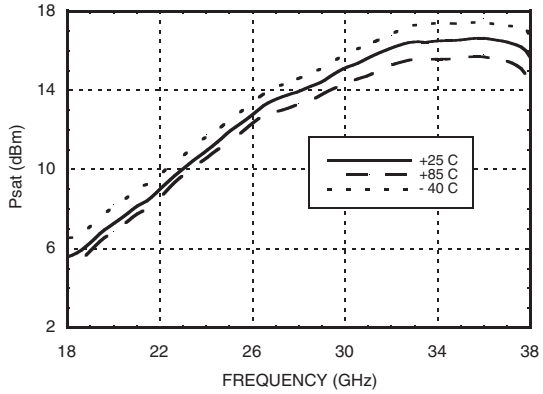
Output P1dB @ Vdd = +5V



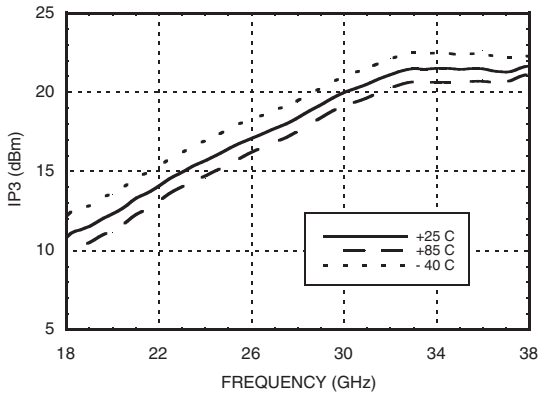
Psat @ Vdd = +3V



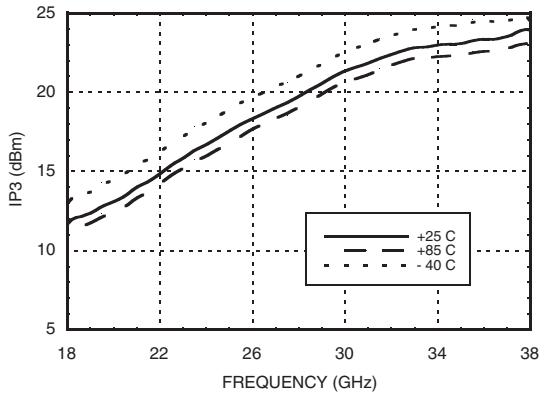
Psat @ Vdd = +5V



Output IP3 @ Vdd = +3V



Output IP3 @ Vdd = +5V



HMC263LP4E

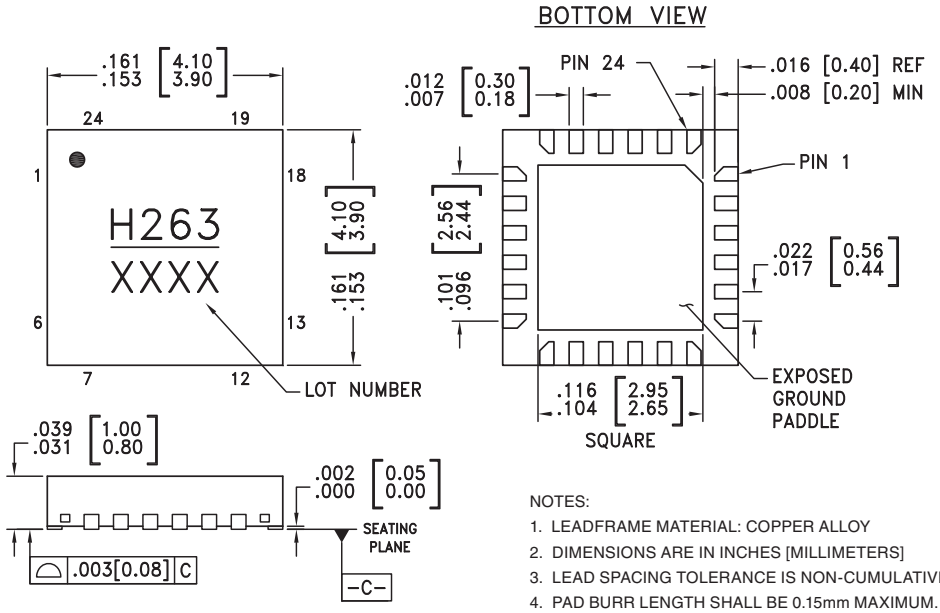
GaAs MMIC LOW NOISE AMPLIFIER, 24 - 36 GHz

Absolute Maximum Ratings

Drain Bias Voltage (Vdd1, Vdd2)	+5.5 Vdc
RF Input Power (RFIN)(Vdd = +3 Vdc)	-5 dBm
Channel Temperature	175 °C
Continuous Pdiss (T = 85 °C) (derate 7.7 mW/°C above 85 °C)	0.7 W
Thermal Resistance (channel to ground paddle)	130 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



NOTES:

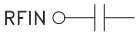
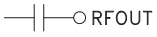
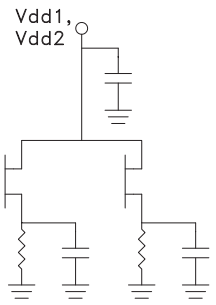
1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Package Information

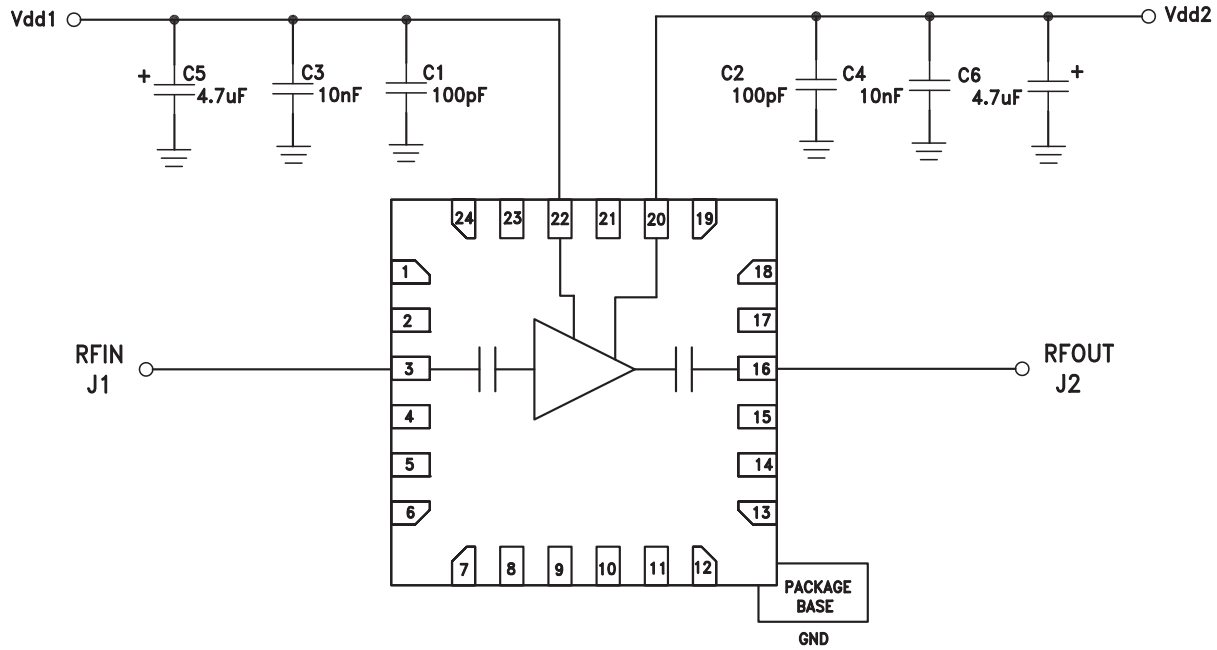
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [1]
HMC263LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL3 [2]	H263 XXXX

[1] 4-Digit lot number XXXX
[2] Max peak reflow temperature of 260 °C

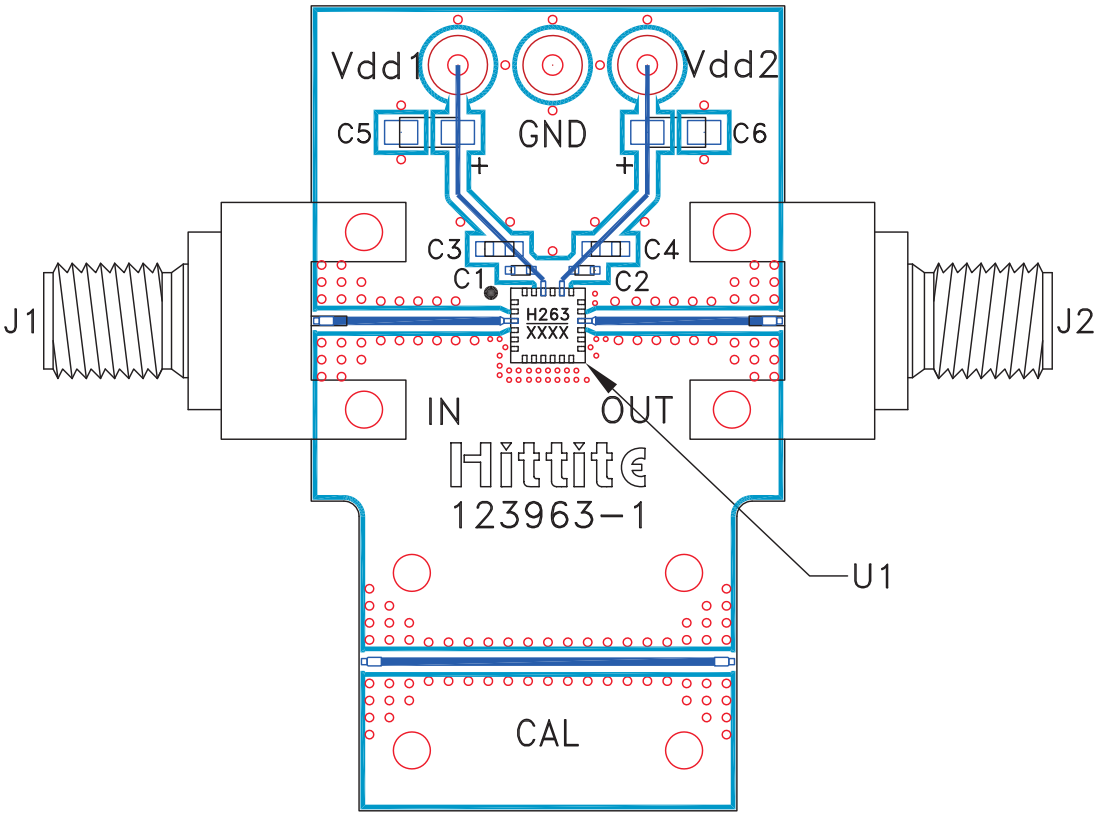
Pin Description

Pin Number	Function	Description	Interface Schematic
1, 2, 4 - 7, 12 - 15, 17 - 19, 24	GND	Package bottom has exposed metal paddle that must be connected to RF/DC ground.	
3	RFIN	This pin is AC coupled and matched to 50 Ohm.	
8 - 11, 21, 23	N/C	Not connected.	
16	RFOUT	This pin is AC coupled and matched to 50 Ohm.	
22, 20	Vdd1, Vdd2	Power supply for the 4-stage amplifier. See application circuit for required external components.	

Application Circuit



Evaluation PCB



List of Materials for Evaluation PCB 123965 [1]

Item	Description
J1, J2	PCB Mount K Connector
J3 - J5	DC Pin
C1, C2	100 pF Capacitor, 0402 Pkg.
C3, C4	10 nF Capacitor, 0603 Pkg.
C5, C6	4.7 µF Capacitor, Tantalum
U1	HMC263LP4E
PCB [2]	123963 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350 or Arlon 25 FR

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and package bottom should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

Notes: